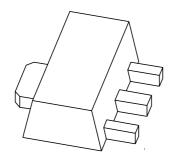
DISCRETE SEMICONDUCTORS

DATA SHEET



PXT4403 PNP switching transistor

Product data sheet Supersedes data of 1999 Apr 14 2004 Nov 22



PNP switching transistor

PXT4403

FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

APPLICATIONS

• Switching and linear amplification.

DESCRIPTION

PNP switching transistor in a SOT89 plastic package. NPN complement: PXT4401.

MARKING

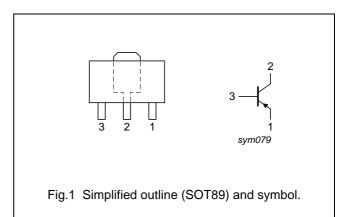
| TYPE NUMBER | MARKING CODE(1) |
|-------------|-----------------|
| PXT4403 | *2T |

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | emitter |
| 2 | collector |
| 3 | base |



ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | | |
|--------------|----------------------|--|-------|--|
| TIPE NOWIBER | NAME DESCRIPTION VEF | | | |
| PXT4403 | SC-62 | plastic surface mounted package; collector pad for good heat transfer; 3 leads | SOT89 | |

PNP switching transistor

PXT4403

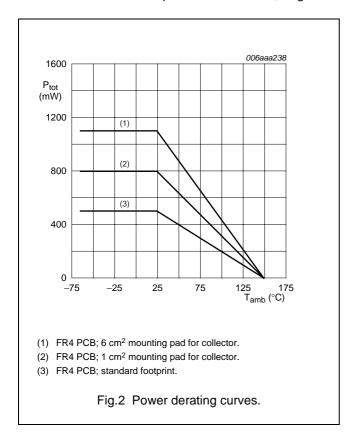
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|--------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | -40 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | -40 | V |
| V _{EBO} | emitter-base voltage | open collector | _ | -5 | V |
| I _C | collector current (DC) | | _ | -600 | mA |
| I _{CM} | peak collector current | | - | -800 | mA |
| I _{BM} | peak base current | | _ | -200 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | |
| | | note 1 | _ | 0.5 | W |
| | | note 2 | _ | 0.8 | W |
| | | note 3 | _ | 1.1 | W |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |

Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 6 cm².



PNP switching transistor

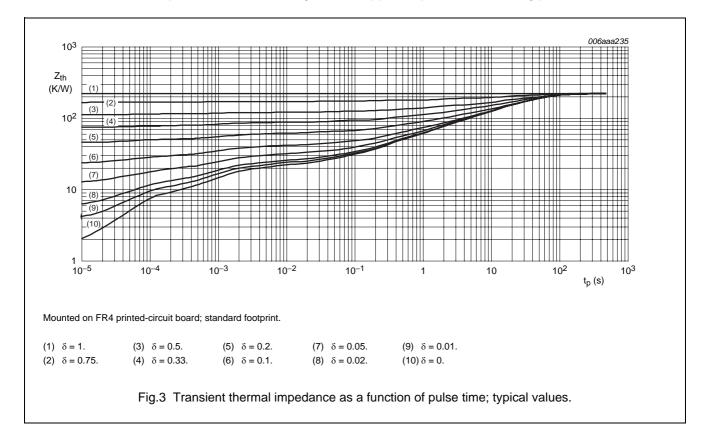
PXT4403

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|-------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to | in free air | | |
| | ambient | note 1 | 250 | K/W |
| | | note 2 | 156 | K/W |
| | | note 3 | 113 | K/W |
| R _{th(j-s)} | thermal resistance from junction to soldering point | | 30 | K/W |

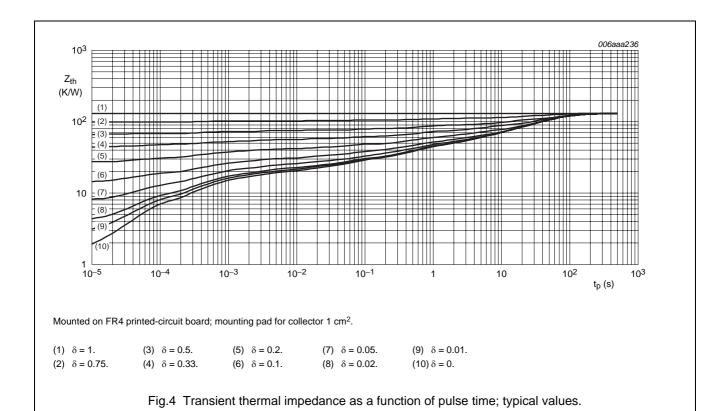
Notes

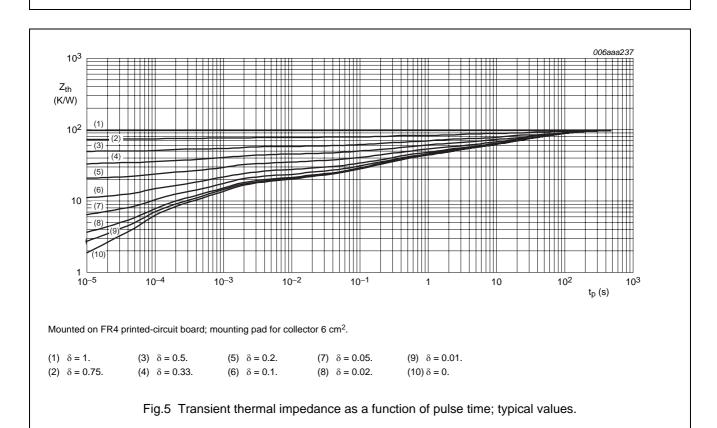
- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 6 cm².



PNP switching transistor

PXT4403





PNP switching transistor

PXT4403

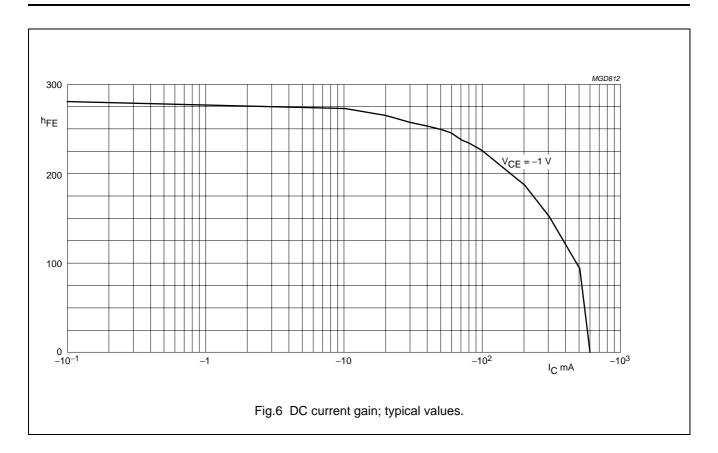
CHARACTERISTICS

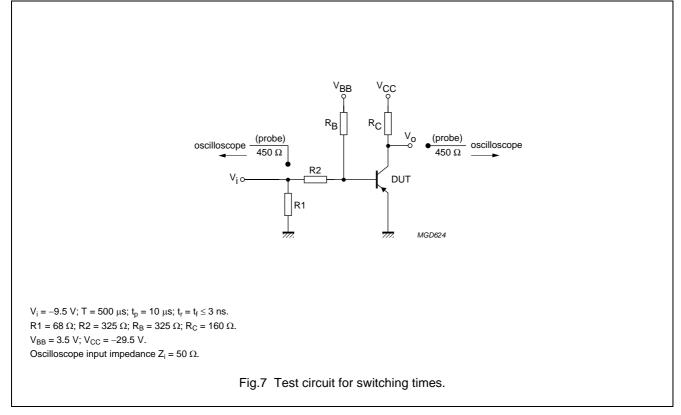
 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|---|--|------|------|------|
| I _{CBO} | collector-base cut-off current | I _E = 0 A; V _{CB} = -40 V | _ | -50 | nA |
| I _{EBO} | emitter-base cut-off current | I _C = 0 A; V _{EB} = -5 V | _ | -50 | nA |
| h _{FE} | DC current gain | $I_C = -0.1 \text{ mA}; V_{CE} = -1 \text{ V}$ | 30 | _ | |
| | | $I_C = -1 \text{ mA}; V_{CE} = -1 \text{ V}$ | 60 | - | |
| | | $I_C = -10 \text{ mA}; V_{CE} = -1 \text{ V}$ | 100 | - | |
| | | $I_C = -150 \text{ mA}; V_{CE} = -2 \text{ V}$ | 100 | 300 | |
| | | $I_C = -500 \text{ mA}; V_{CE} = -2 \text{ V}$ | 20 | - | |
| V _{CEsat} | collector-emitter saturation | $I_C = -150 \text{ mA}; I_B = -15 \text{ mA}$ | _ | -400 | mV |
| | voltage | $I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$ | _ | -750 | mV |
| V _{BEsat} | base-emitter saturation voltage | $I_C = -150 \text{ mA}; I_B = -15 \text{ mA}$ | _ | -950 | mV |
| | | $I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$ | _ | -1.3 | V |
| C _c | collector capacitance | $I_E = i_e = 0 \text{ A}; V_{CB} = -10 \text{ V}; f = 1 \text{ MHz}$ | _ | 8.5 | pF |
| C _e | emitter capacitance | $I_C = i_c = 0 \text{ A}; V_{EB} = -500 \text{ mV}; f = 1 \text{ MHz}$ | _ | 35 | pF |
| f _T | transition frequency | $I_C = -20 \text{ mA}; V_{CE} = -10 \text{ V}; f = 100 \text{ MHz}$ | 200 | - | MHz |
| Switching t | Switching times (between 10% and 90% levels); (see Fig.7) | | | | |
| t _{on} | turn-on time | $I_{Con} = -150 \text{ mA}; I_{Bon} = -15 \text{ mA};$ | _ | 40 | ns |
| t _d | delay time | I _{Boff} = 15 mA | _ | 15 | ns |
| t _r | rise time | | _ | 30 | ns |
| t _{off} | turn-off time | | _ | 350 | ns |
| t _s | storage time | | _ | 300 | ns |
| t _f | fall time | | _ | 50 | ns |

PNP switching transistor

PXT4403





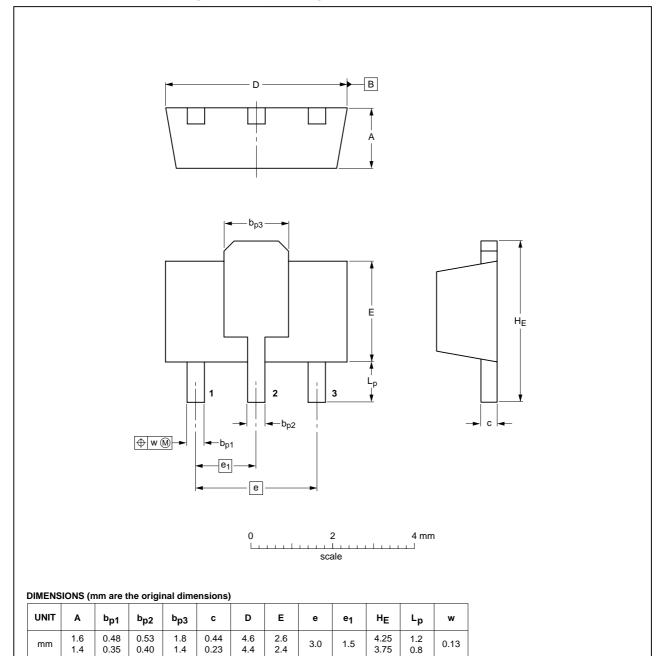
PNP switching transistor

PXT4403

PACKAGE OUTLINE

Plastic surface-mounted package; collector pad for good heat transfer; 3 leads

SOT89



| OUTLINE | REFERENCES | | EUROPEAN | ISSUE DATE | | |
|---------|------------|--------|----------|------------|------------|----------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT89 | | TO-243 | SC-62 | | | -04-08-03 06-03-16 |

PNP switching transistor

PXT4403

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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Printed in The Netherlands R75/04/pp10 Date of release: 2004 Nov 22 Document order number: 9397 750 13899



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